



## Einladung

Es spricht: **Dr. Fei Ding**  
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Zeit: **Donnerstag, 30. Juni 2016, 15:00 Uhr**

Ort: **Technische Universität Berlin  
Institut für Festkörperphysik  
Hardenbergstraße 36, 10623 Berlin  
Raum EW 431**

Thema: **„Semiconductor entangled photon sources:  
Electrical injection and Energy tunability“**

### Abstract:

Entangled photon sources are playing a crucial role in photonic quantum information science. Self-assembled semiconductor quantum dots (QDs) are among the most promising sources for on-demand generation of entangled photons. Compared to other candidate systems, QDs have an undeniable advantage of being compatible with mature semiconductor technologies.

For the long-pursued entanglement swapping and the hybrid coupling schemes, the wavelength (energy) of the entangled photons must be tunable. By embedding the QDs in stretchable nanomembranes, we have developed a unique strain tuning technique to engineer the QDs.[1-2] In this talk I will first explain the technique by introducing a wavelength tunable single photon source.[3-4] Then an electrically triggered entangled photon source with QDs will be introduced.[5] We have demonstrated an entangled light-emitting-diode with ultra-fast operation speed and high yield. Finally our latest generation of strain engineering platform will be presented, where the III-V QD sources are integrated on silicon substrate with ultra-small footprints,[6] and wavelength tunable entangled photons are demonstrated. These results will lead to several exciting quantum photonic experiments.

### References:

- [1] F. Ding\*... O. G. Schmidt **Phys. Rev. Lett.** 104, 067405 (2010)
- [2] F. Ding\*... O. G. Schmidt **Nano Lett.** 10, 3453 (2010)
- [3] J. Zhang...F. Ding\*, O. G. Schmidt **Nano Lett.** 13, 5808 (2013)
- [4] Y. Huo...F. Ding... O. G. Schmidt **Nature Phys.** 10, 46 (2014)
- [5] J. Zhang...F. Ding\*, O. G. Schmidt **Nature Commun.** 6, 10067 (2015)
- [6] Y. Chen...F. Ding\*, O. G. Schmidt **Nature Commun.** 7, 10387 (2016)

Gäste sind herzlich willkommen!

Prof. Dr. S. Reitzenstein